



PIMC31-Q

500 mA, 50 V NPN/PNP double resistor-equipped transistor;
R1 = 1 k Ω , R2 = 10 k Ω

20 April 2023

Product data sheet

1. General description

500 mA, 50 V NPN/PNP double Resistor-Equipped Transistor (RET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- 500 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Digital application in automotive and industrial segments
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
V _{CEO}	collector-emitter voltage	open base	[1]	-	-	50	V
I _O	output current		[1]	-	-	500	mA
R1	bias resistor 1 (input)		[2]	0.7	1	1.3	k Ω
R2/R1	bias resistor ratio		[2]	9	10	11	

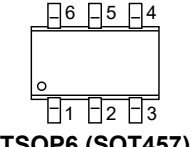
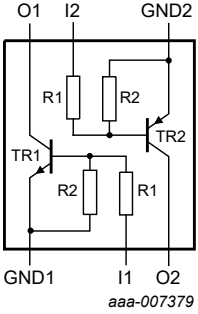
[1] For the PNP transistor with negative polarity.

[2] See section "Test information" for resistor calculation and test conditions.

500 mA, 50 V NPN/PNP double resistor-equipped transistor; R1 = 1 k Ω , R2 = 10 k Ω

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 <p>TSOP6 (SOT457)</p>	 <p>aaa-007379</p>
2	I1	input (base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input (base) TR2		
6	O1	output (collector) TR1		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PIMC31-Q	TSOP6	plastic, surface-mounted package (SC-74; TSOP6); 6 leads	SOT457

7. Marking

Table 4. Marking codes

Type number	Marking code
PIMC31-Q	ZH

8. Limiting values

Table 5. Limiting values

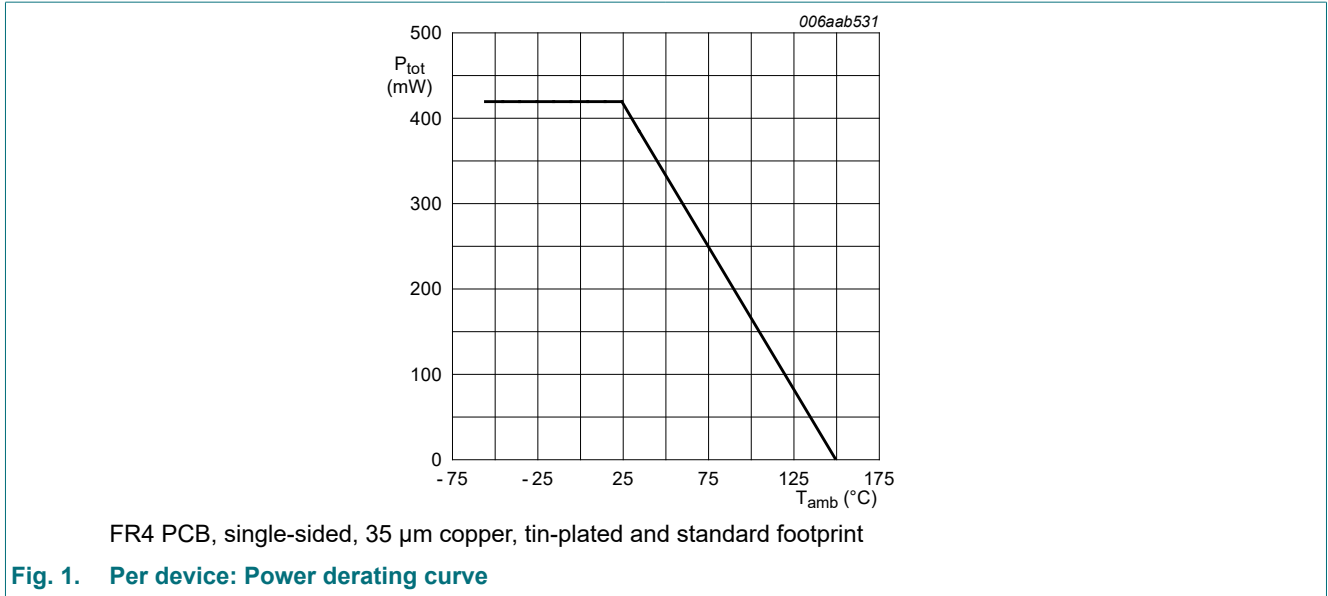
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transistor						
V_{CBO}	collector-base voltage	open emitter	[1]	-	50	V
V_{CEO}	collector-emitter voltage	open base	[1]	-	50	V
V_{EBO}	emitter-base voltage	open collector	[1]	-	5	V
V_i	input voltage	TR1 (NPN)		-5	10	V
		TR2 (PNP)		-10	5	V
I_O	output current		[1]	-	500	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ }^\circ\text{C}$	[2]	-	290	mW
Per device						
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ }^\circ\text{C}$	[2]	-	420	mW
T_j	junction temperature			-	150	$^\circ\text{C}$
T_{amb}	ambient temperature			-55	150	$^\circ\text{C}$

500 mA, 50 V NPN/PNP double resistor-equipped transistor; R1 = 1 kΩ, R2 = 10 kΩ

Symbol	Parameter	Conditions	Min	Max	Unit
T _{stg}	storage temperature		-65	150	°C

- [1] For the PNP transistor with negative polarity.
- [2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 μm copper, tin-plated and standard footprint.

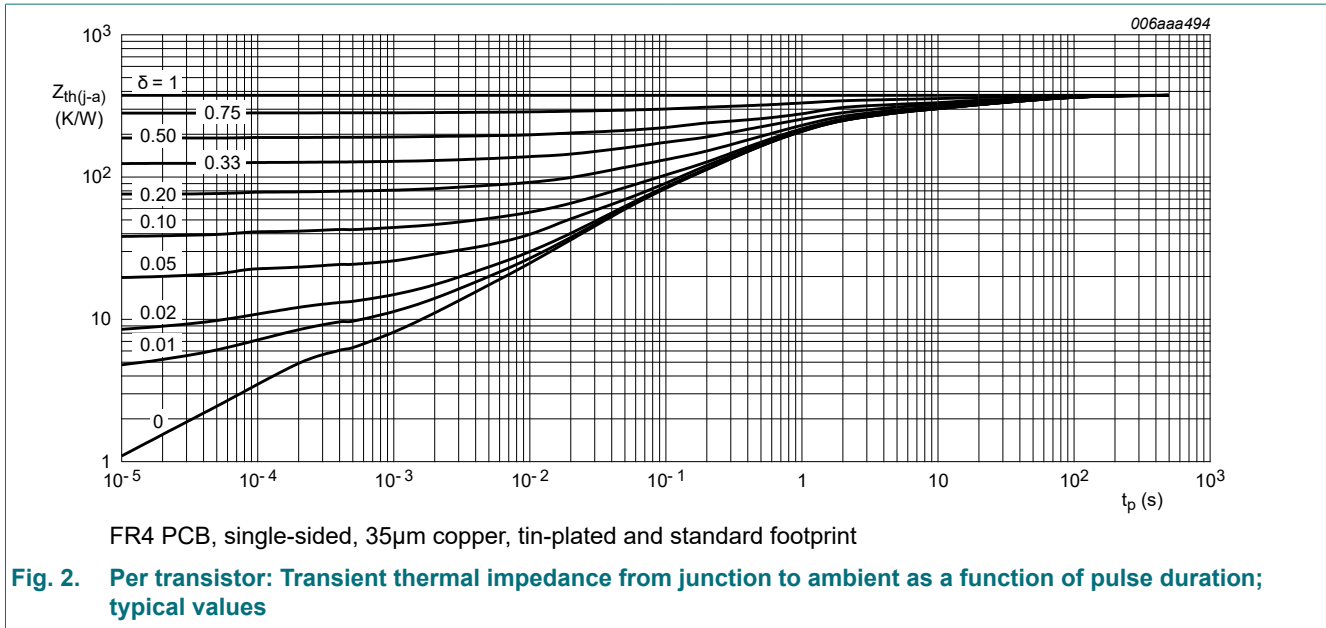


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor						
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	431	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	105	K/W
Per device						
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	298	K/W

- [1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.



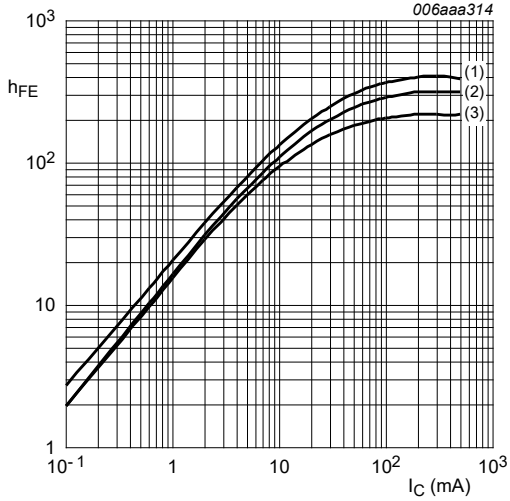
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \mu A; I_E = 0 A; T_{amb} = 25 \text{ }^\circ C$	[1]	50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = 2 \text{ mA}; I_B = 0 A; T_{amb} = 25 \text{ }^\circ C$	[1]	50	-	-	V
I_{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 A; T_{amb} = 25 \text{ }^\circ C$	[1]	-	-	100	nA
I_{CEO}	collector-emitter cut-off current	$V_{CE} = 50 \text{ V}; I_B = 0 A; T_{amb} = 25 \text{ }^\circ C$	[1]	-	-	0.5	µA
I_{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_C = 0 A; T_{amb} = 25 \text{ }^\circ C$	[1]	-	-	0.72	mA
h_{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_C = 50 \text{ mA}; T_{amb} = 25 \text{ }^\circ C$	[1]	70	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}; T_{amb} = 25 \text{ }^\circ C$	[1]	-	-	300	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_C = 100 \mu A$	[1]	0.3	0.6	1	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_C = 20 \text{ mA}; T_{amb} = 25 \text{ }^\circ C$	[1]	0.4	0.8	1.4	V
R1	bias resistor 1 (input)		[2]	0.7	1	1.3	kΩ
R2/R1	bias resistor ratio		[2]	9	10	11	
TR1 (NPN)							
C_c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 A; i_e = 0 A; f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^\circ C$		-	7	-	pF
TR2 (PNP)							
C_c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = 0 A; i_e = 0 A; f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^\circ C$		-	11	-	pF

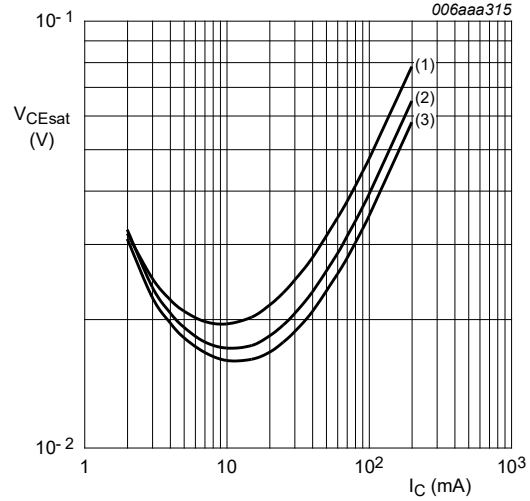
[1] For the PNP transistor with negative polarity.

[2] See section "Test information" for resistor calculation and test conditions.



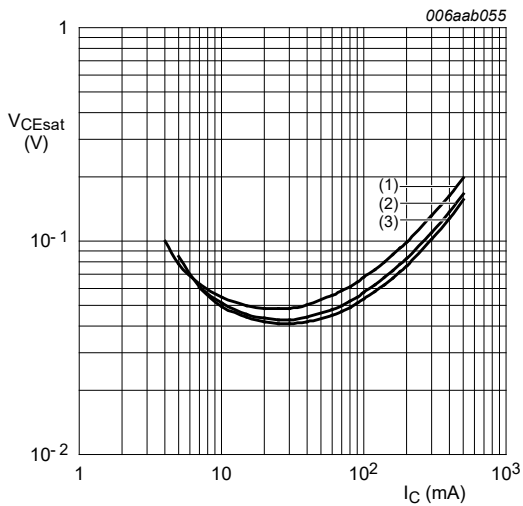
$V_{CE} = 5\text{ V}$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 3. TR1 (NPN): DC current gain as a function of collector current; typical values



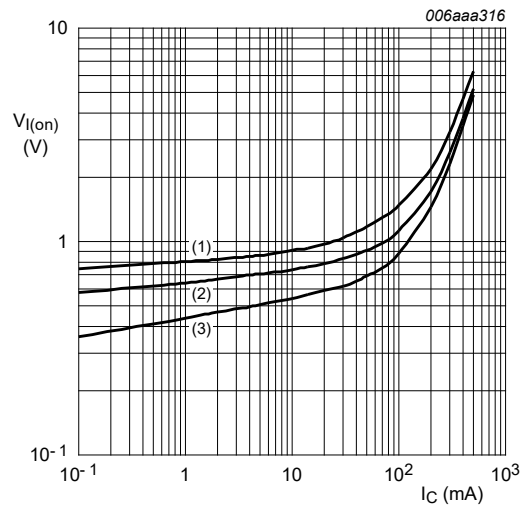
$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 4. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



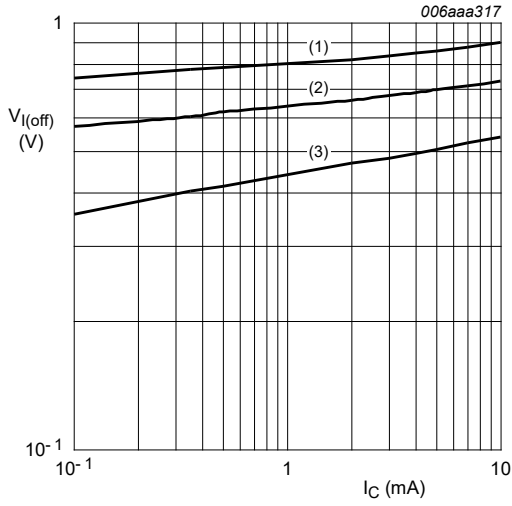
$I_C/I_B = 50$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 5. TR1 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



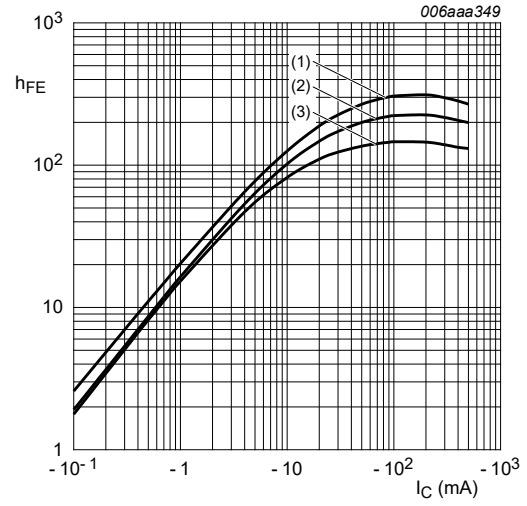
$V_{CE} = 0.3\text{ V}$
 (1) $T_{amb} = -40\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 100\text{ °C}$

Fig. 6. TR1 (NPN): On-state input voltage as a function of collector current; typical values



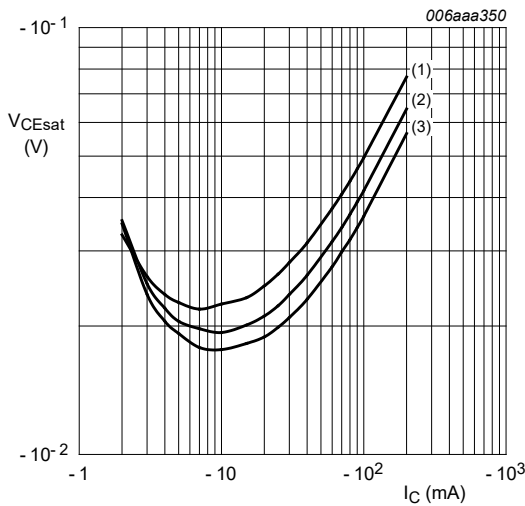
$V_{CE} = 5\text{ V}$
 (1) $T_{amb} = -40\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = 100\text{ °C}$

Fig. 7. TR1 (NPN): Off-state input voltage as a function of collector current; typical values



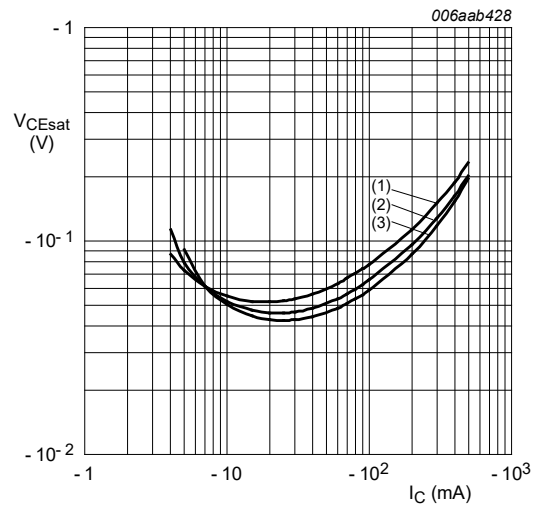
$V_{CE} = -5\text{ V}$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 8. TR2 (PNP): DC current gain as a function of collector current; typical values



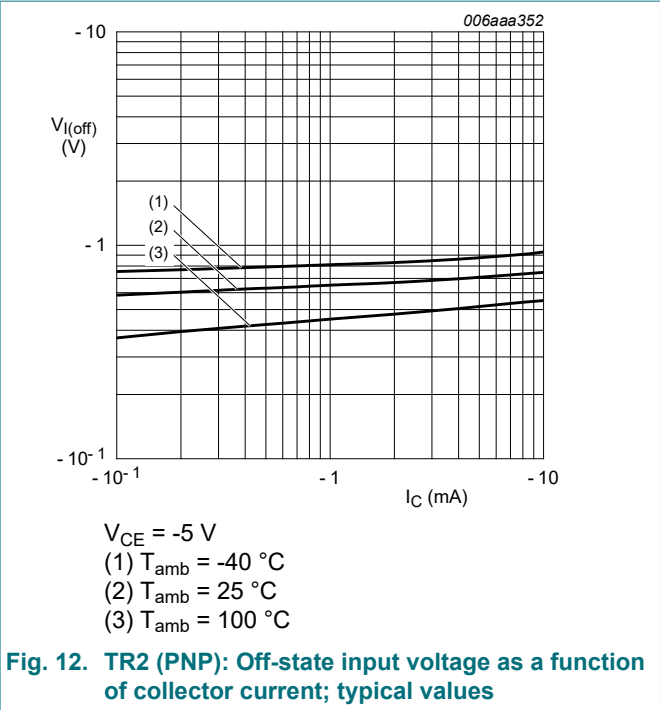
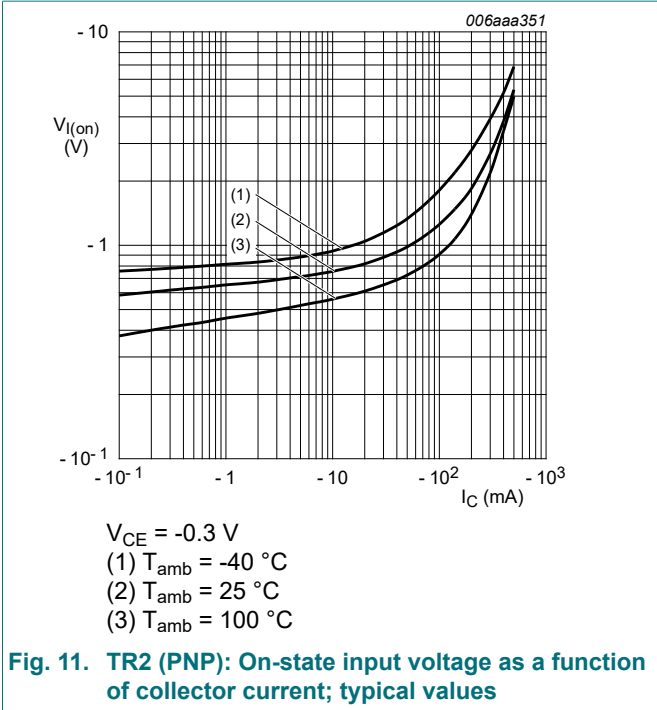
$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 9. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 50$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 10. TR2 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

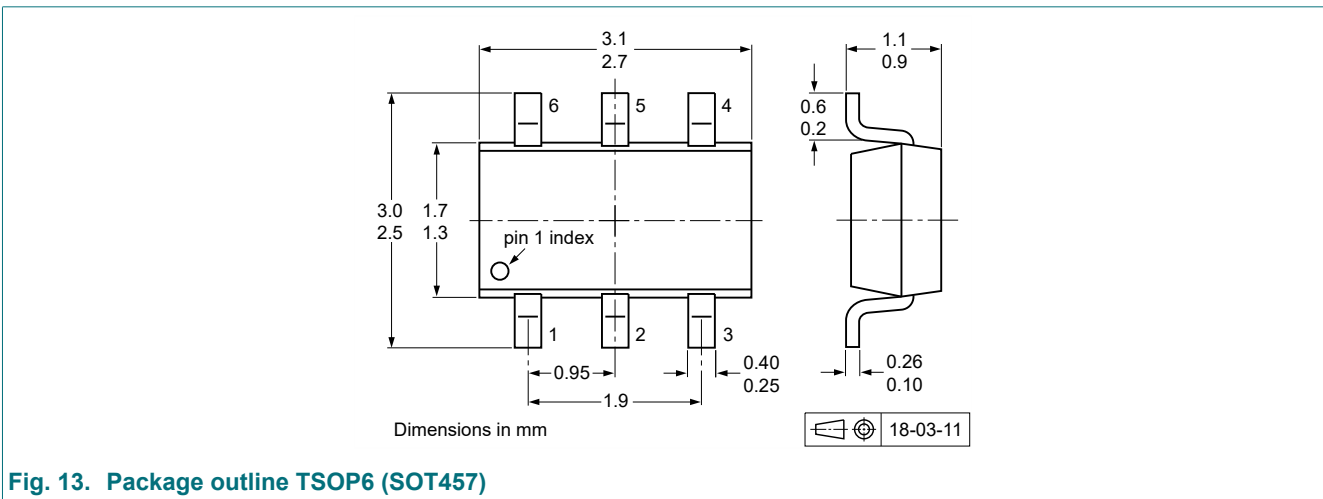


11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Soldering

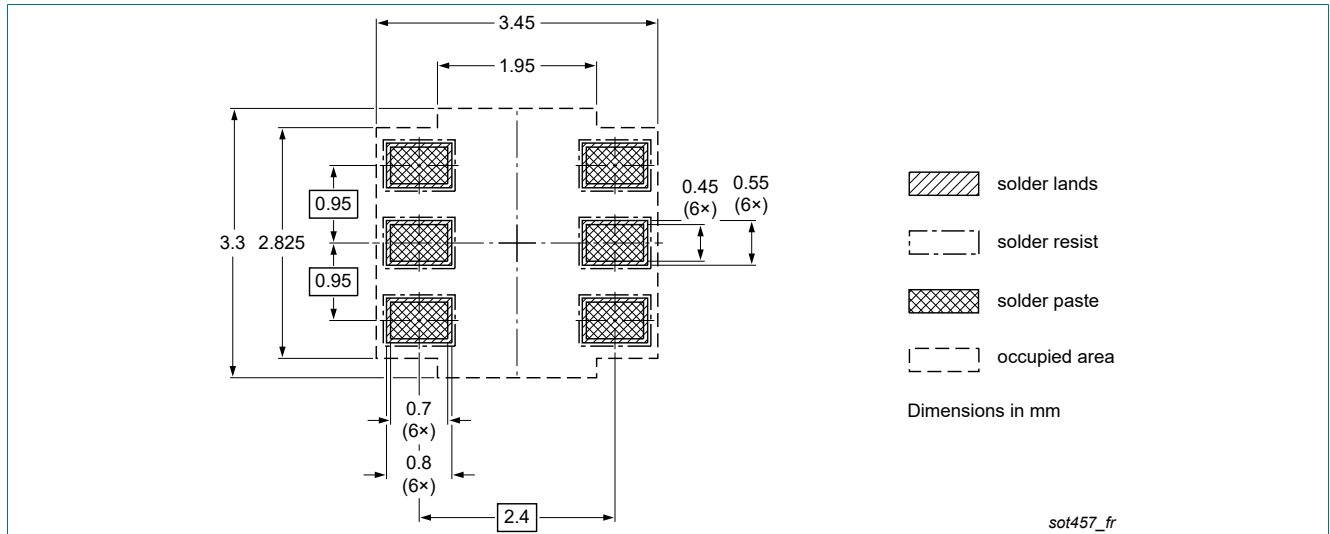


Fig. 14. Reflow soldering footprint for TSOP6 (SOT457)

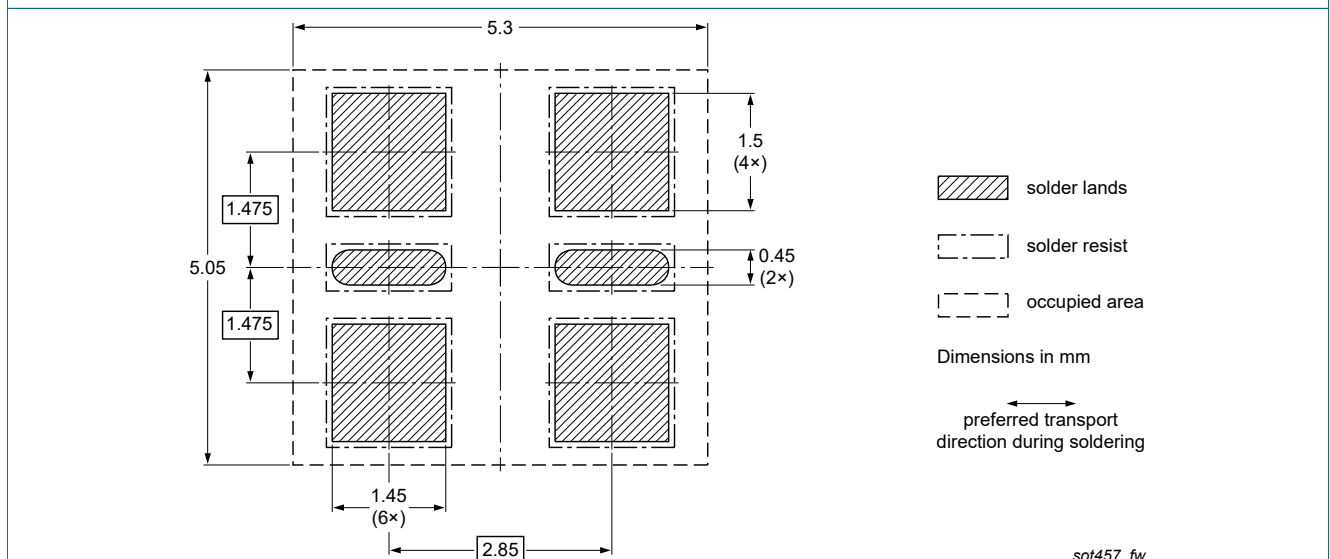


Fig. 15. Wave soldering footprint for TSOP6 (SOT457)

500 mA, 50 V NPN/PNP double resistor-equipped transistor; R1 = 1 kΩ, R2 = 10 kΩ

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PIMC31-Q v.1	20230420	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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Contents

1. General description.....	1
2. Features and benefits.....	1
3. Applications.....	1
4. Quick reference data.....	1
5. Pinning information.....	2
6. Ordering information.....	2
7. Marking.....	2
8. Limiting values.....	2
9. Thermal characteristics.....	3
10. Characteristics.....	4
11. Test information.....	7
12. Package outline.....	7
13. Soldering.....	8
14. Revision history.....	9
15. Legal information.....	10

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Date of release: 20 April 2023
